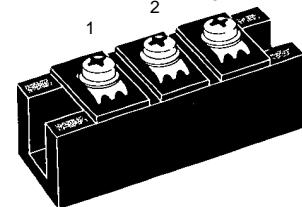
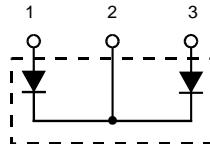


# Fast Recovery Epitaxial Diode (FRED) Module

## MEK 350-02 DA

$V_{RRM} = 200 \text{ V}$   
 $I_{FAVM} = 356 \text{ A}$   
 $t_{rr} = 150 \text{ ns}$

$V_{RSM}$	$V_{RRM}$	Type
V	V	
200	200	MEK 350-02DA

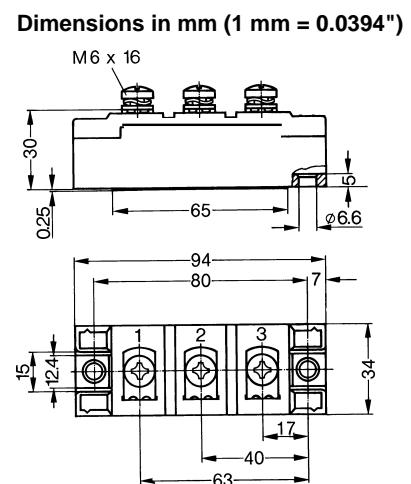


Symbol	Test Conditions	Maximum Ratings	
$I_{FRMS}$	$T_c = 75^\circ\text{C}$	503	A
$I_{FAVM}$ ①	$T_c = 75^\circ\text{C}$ ; rectangular, $d = 0.5$	356	A
$I_{FPM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	1800	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	2400	A
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	2640	A
$I^2t$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	2160	A
	$T_{VJ} = 150^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	2380	A
		28800	$\text{A}^2\text{s}$
		29300	$\text{A}^2\text{s}$
$T_{VJ}$		-40...+150	$^\circ\text{C}$
$T_{stg}$		-40...+125	$^\circ\text{C}$
$T_{Smax}$		110	$^\circ\text{C}$
$P_{tot}$	$T_c = 25^\circ\text{C}$	875	W
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$	3000	$\text{V}_-$
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3600	$\text{V}_-$
$M_d$	Mounting torque (M6) Terminal connection torque (M6)	2.25-2.75/20-25 Nm/lb.in. 4.50-5.50/40-48 Nm/lb.in.	
$d_s$	Creeping distance on surface	12.7	mm
$d_a$	Strike distance through air	9.6	mm
$a$	Maximum allowable acceleration	50	$\text{m/s}^2$
<b>Weight</b>		150	g

Symbol	Test Conditions	Characteristic Values (per diode)	
		typ.	max.
$I_R$	$T_{VJ} = 25^\circ\text{C}$ $V_R = V_{RRM}$ $T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$ $T_{VJ} = 125^\circ\text{C}$ $V_R = 0.8 \cdot V_{RRM}$	3 2 80	mA mA mA
$V_F$	$I_F = 150 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$ $I_F = 260 \text{ A}$ ; $T_{VJ} = 125^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$	0.80 0.98 0.92 1.07	V V V V
$V_{TO}$	For power-loss calculations only	0.53 1.29	V $\text{m}\Omega$
$r_T$			
$R_{thH}$	DC current	0.228	K/W
$R_{thJC}$	DC current	0.143	K/W
$t_{rr}$	$I_F = 300 \text{ A}$ $V_R = 100 \text{ V}$ $-di/dt = 200 \text{ A}/\mu\text{s}$	150	ns A A
$t_{rr}$	$T_{VJ} = 100^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 100^\circ\text{C}$	200 9 15	ns A A

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_R = 0.6 V_{RRM}$ , duty cycle  $d = 0.5$   
Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions



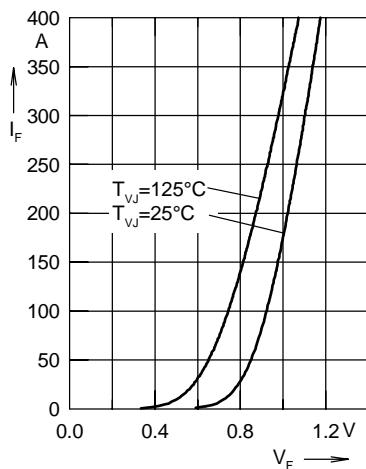


Fig. 1 Forward current  $I_F$  versus voltage drop  $V_F$  per leg

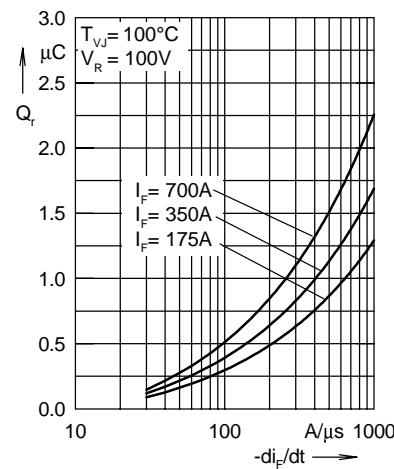


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

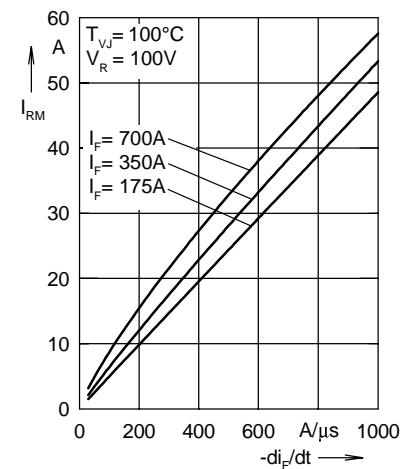


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

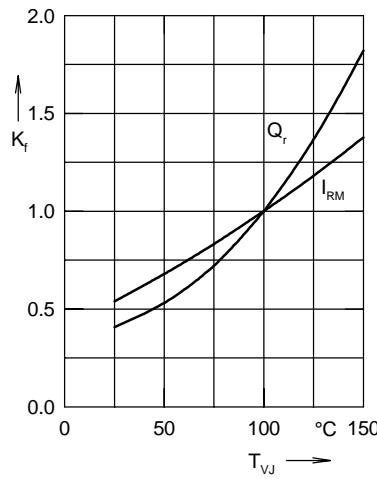


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus junction temperature  $T_{VJ}$

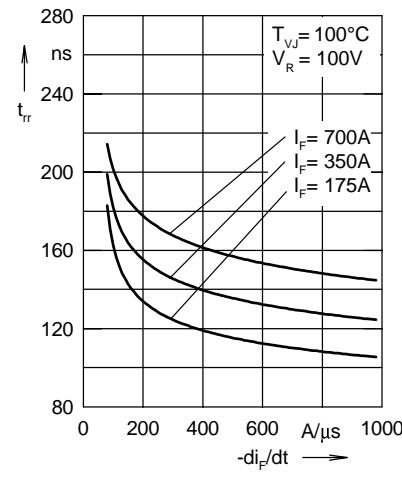


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

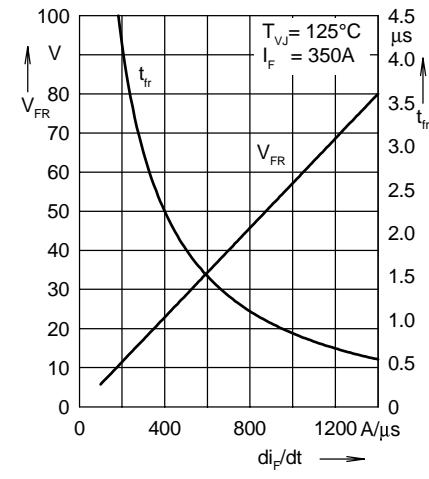


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{rr}$  versus  $di_F/dt$

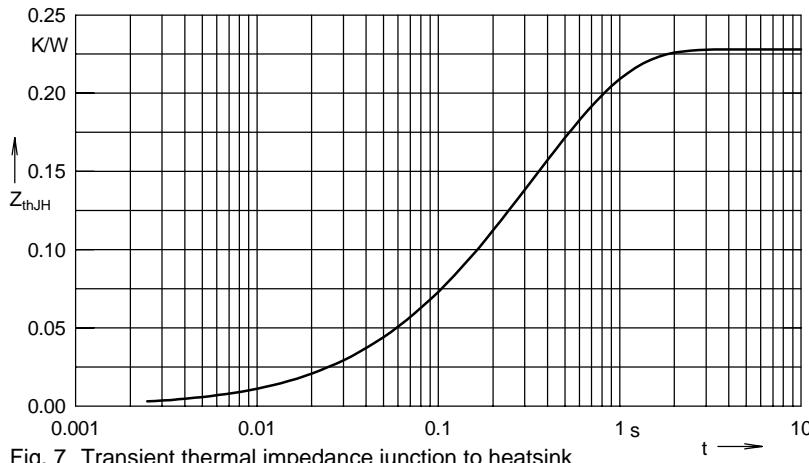


Fig. 7 Transient thermal impedance junction to heatsink

Constants for  $Z_{\theta JS}$  calculation:

i	$R_{\theta hi}$ (K/W)	$t_i$ (s)
1	0.002	0.08
2	0.008	0.024
3	0.054	0.112
4	0.164	0.464